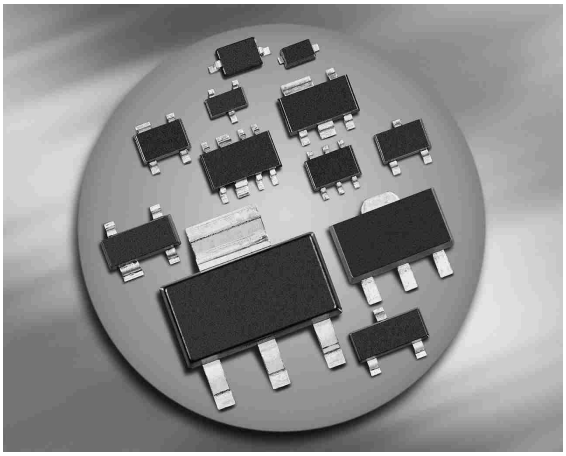
PNP Silicon Switching Transistors

- High DC current gain: 0.1 mA to 100 mA
- Low collector-emitter saturation voltage
- For SMBT3906S and SMBT3906U:
  Two (galvanic) internal isolated transistor with good matching in one package
- Complementary types:
  SMBT3904...MMBT3904 (NPN)
- SMBT3906S/ U: for orientation in reel
  see package information below
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101



AEC Qualified RoHS

Type	Marking	Pin Configuration						Package
SMBT3906/ MMBT3906	s2A	1=B	2=E	3=C	-	-	-	SOT23
SMBT3906S	s2A	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SOT363
SMBT3906U	s2A	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SC74

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	40	V
Collector-base voltage	V_{CBO}	40	
Emitter-base voltage	V_{EBO}	6	
Collector current	I_C	200	mA
Total power dissipation-	P_{tot}		mW
$T_S \leq 71$°C, SOT23, MMBT3906		330	
$T_S \leq 115$°C, SOT363, MMBT3906S		250	
$T_S \leq 107$°C, SC74, MMBT3906U		330	
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point[1)]	R_{thJS}		mW
SMBT3906/ MMBT3906		≤ 240	
SMBT3906S		≤ 140	
SMBT3906U		≤ 130	

[1]For calculation of R_{thJA} please refer to Application Note AN077 (Thermal Resistance Calculation)

Electrical Characteristics at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage I_C = 1 mA, I_B = 0	$V_{(BR)CEO}$	40	-	-	V
Collector-base breakdown voltage I_C = 10 µA, I_E = 0	$V_{(BR)CBO}$	40	-	-	
Emitter-base breakdown voltage I_E = 10 µA, I_C = 0	$V_{(BR)EBO}$	6	-	-	
Collector-base cutoff current V_{CB} = 30 V, I_E = 0	I_{CBO}	-	-	50	nA
DC current gain[1)]	h_{FE}				-
I_C = 100 µA, V_{CE} = 1 V		60	-	-	
I_C = 1 mA, V_{CE} = 1 V		80	-	-	
I_C = 10 mA, V_{CE} = 1 V		100	-	300	
I_C = 50 mA, V_{CE} = 1 V		60	-	-	
I_C = 100 mA, V_{CE} = 1 V		30	-	-	
Collector-emitter saturation voltage[1)]	V_{CEsat}				V
I_C = 10 mA, I_B = 1 mA		-	-	0.25	
I_C = 50 mA, I_B = 5 mA		-	-	0.4	
Base emitter saturation voltage[1)]	V_{BEsat}				
I_C = 10 mA, I_B = 1 mA		0.65	-	0.85	
I_C = 50 mA, I_B = 5 mA		-	-	0.95	

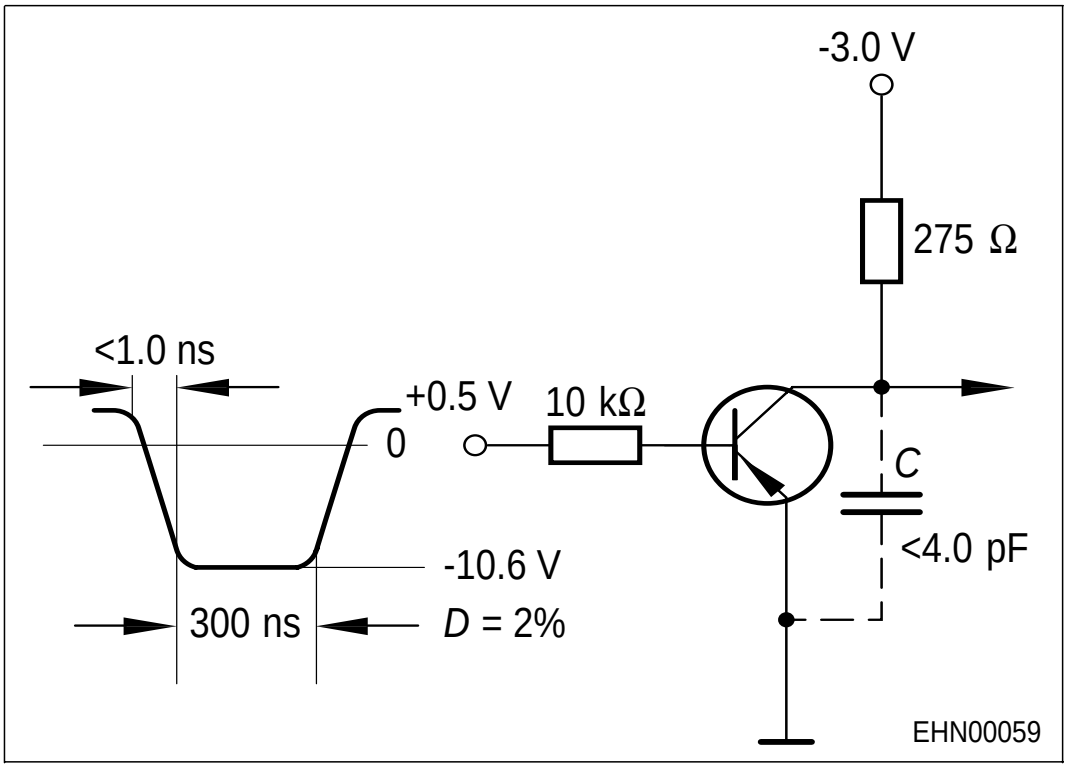
[1]Pulse test: t < 300µs; D < 2%

Electrical Characteristics at T_A = 25°C, unless otherwise specified

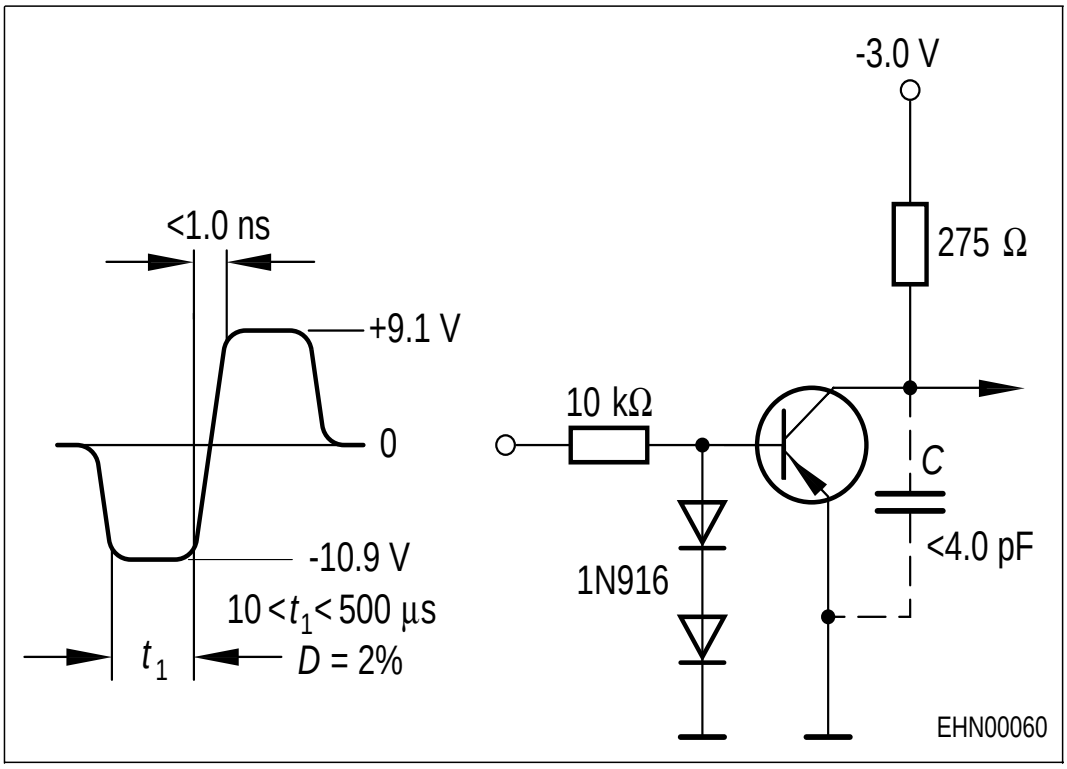
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
AC Characteristics					
Transition frequency I_C = 10 mA, V_{CE} = 20 V, f = 100 MHz	f_T	250	-	-	MHz
Collector-base capacitance V_{CB} = 5 V, f = 1 MHz	C_{cb}	-	-	3.5	pF
Emitter-base capacitance V_{EB} = 0.5 V, f = 1 MHz	C_{eb}	-	-	10	
Delay time V_{CC} = 3 V, I_C = 10 mA, I_{B1} = 1 mA, $V_{BE(off)}$ = 0.5 V	t_d	-	-	35	ns
Rise time V_{CC} = 3 V, I_C = 10 mA, I_{B1} = 1 mA, $V_{BE(off)}$ = 0.5 V	t_r	-	-	35	
Storage time V_{CC} = 3 V, I_C = 10 mA, I_{B1} = I_{B2} = 1 mA	t_{stg}	-	-	225	
Fall time V_{CC} = 3 V, I_C = 10 mA, I_{B1} = I_{B2} = 1 mA	t_f	-	-	75	
Noise figure I_C = 100 µA, V_{CE} = 5 V, f = 1 kHz, Δf = 200 Hz, R_S = 1 kΩ	F	-	-	4	dB

Test circuit

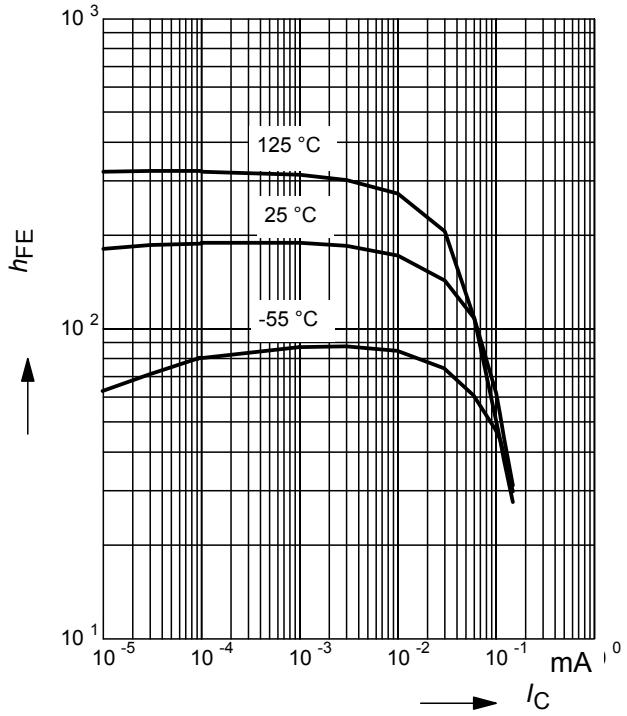
Delay and rise time



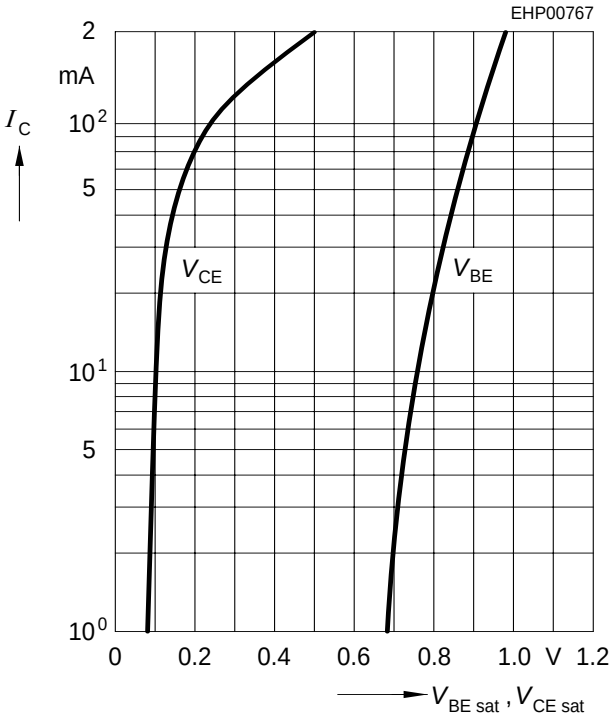
Storage and fall time



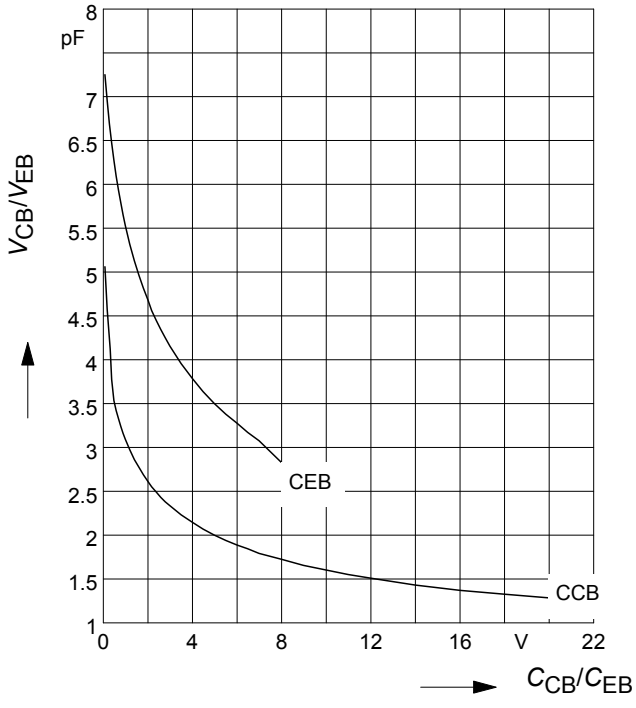
DC current gain $h_{FE} = f(I_C)$
V_{CE} = 1 V



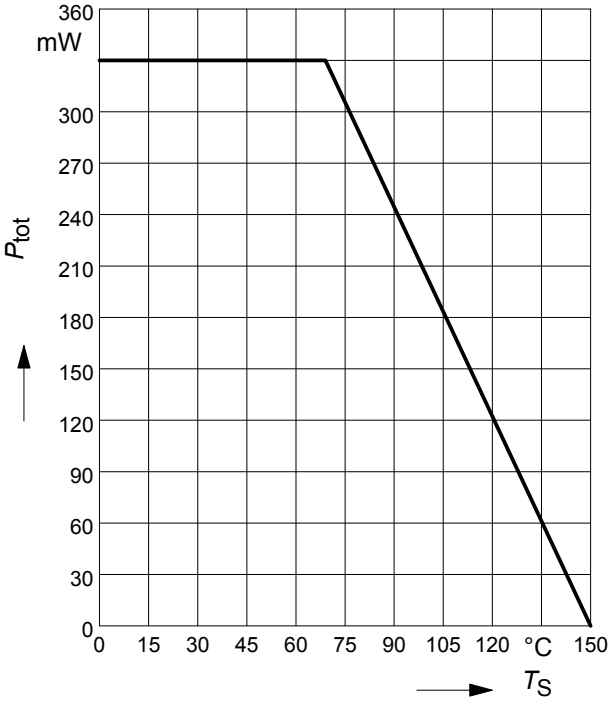
Saturation voltage $I_C = f(V_{BEsat}; V_{CEsat})$
h_{FE} = 10



Collector-base capacitance $C_{cb} = f(V_{CB})$
Emitter-base capacitance $C_{eb} = f(V_{EB})$

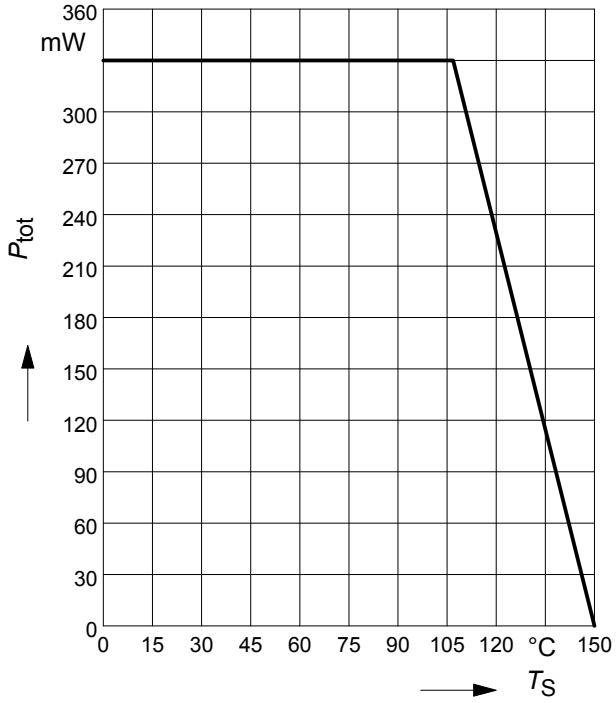


Total power dissipation $P_{tot} = f(T_S)$
SMBT3906



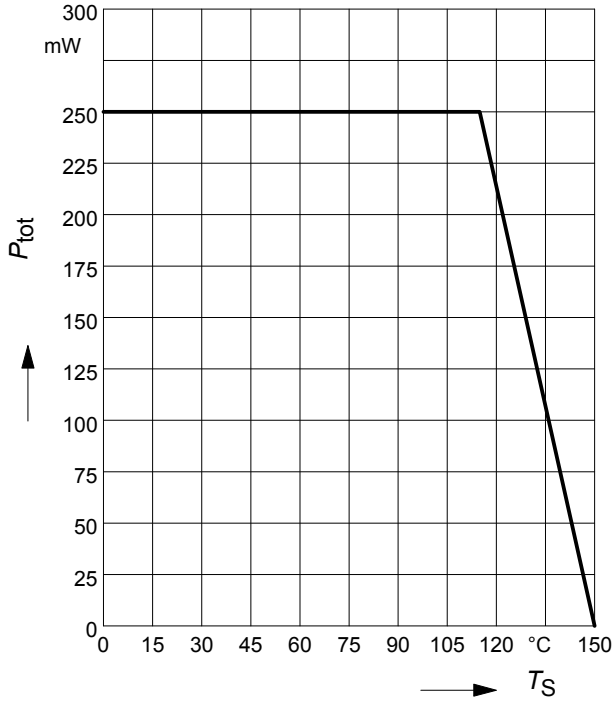
Total power dissipation $P_{tot} = f(T_S)$

SMBT3906U



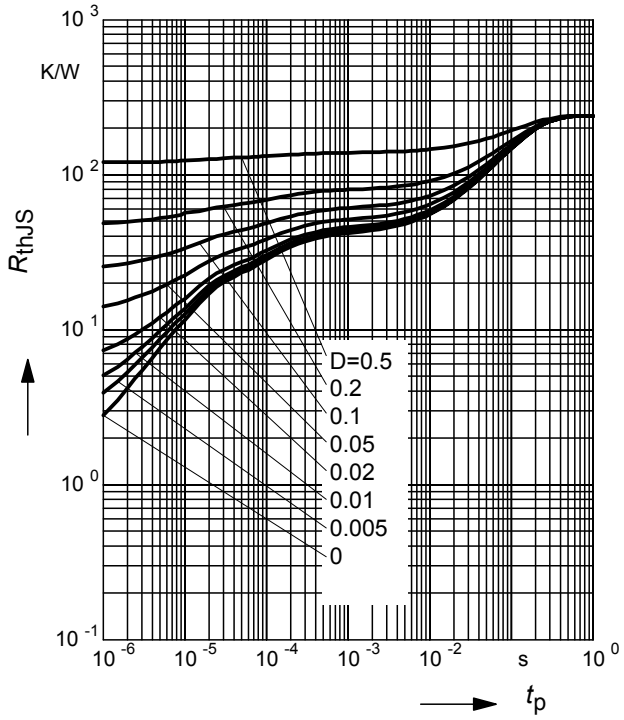
Total power dissipation $P_{tot} = f(T_S)$

SMBT3906S



Permissible Pulse Load $R_{thJS} = f(t_p)$

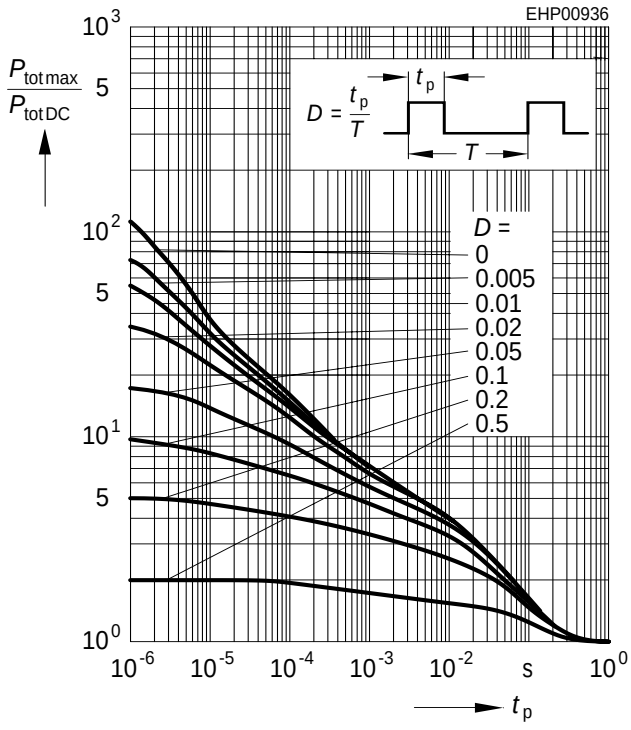
SMBT3906



Permissible Pulse Load

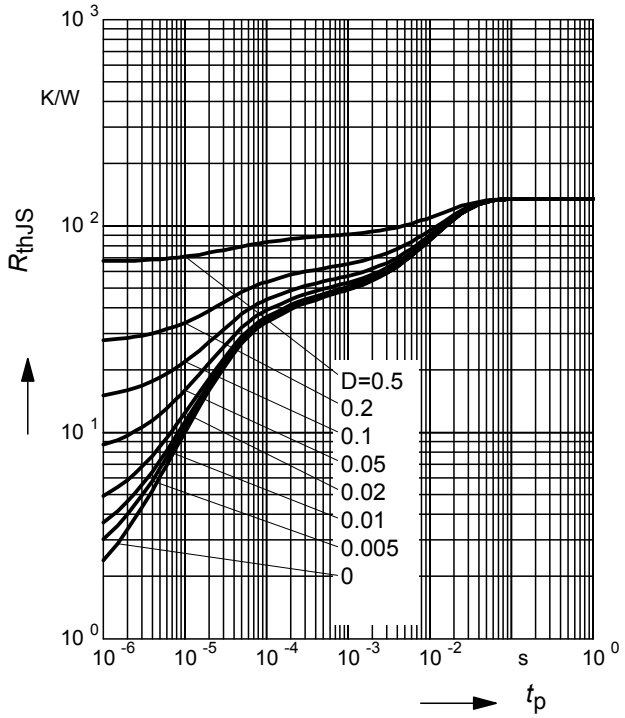
$P_{totmax}/P_{totDC} = f(t_p)$

SMBT3906



Permissible Puls Load $R_{thJS} = f(t_p)$

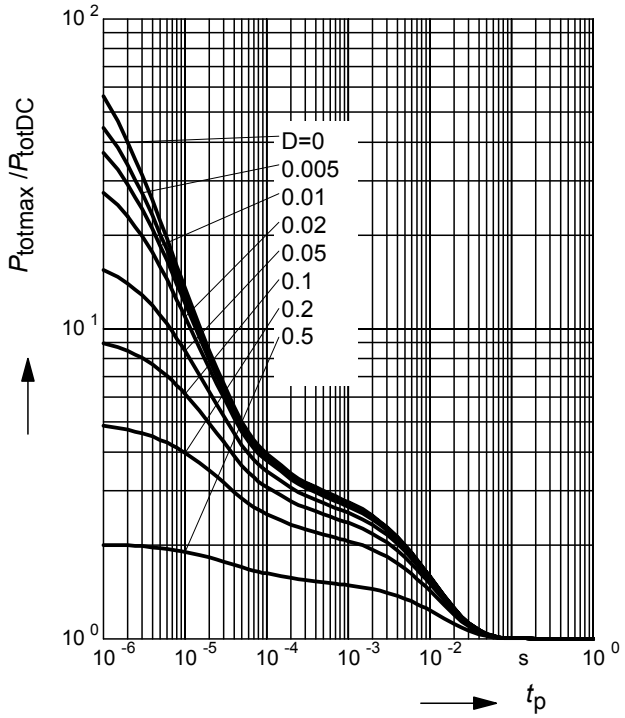
SMBT3906U



Permissible Pulse Load

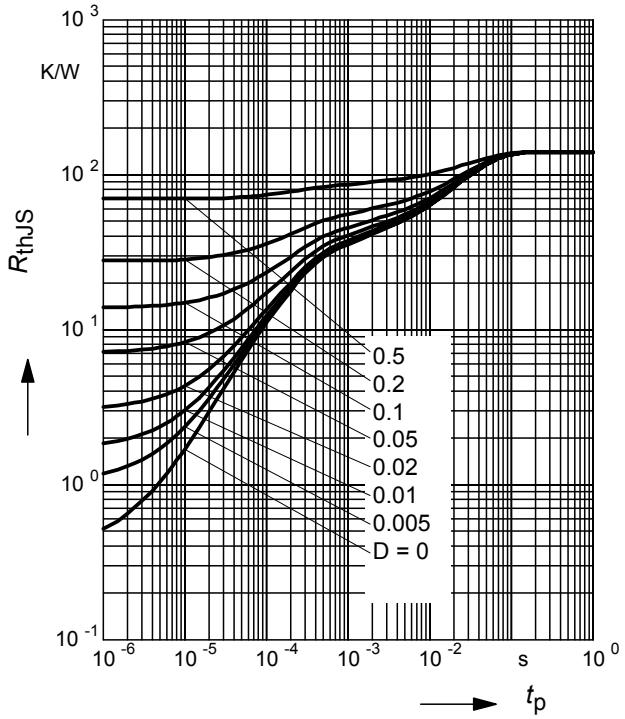
$P_{totmax}/P_{totDC} = f(t_p)$

SMBT3906U



Permissible Pulse Load $R_{thJS} = f(t_p)$

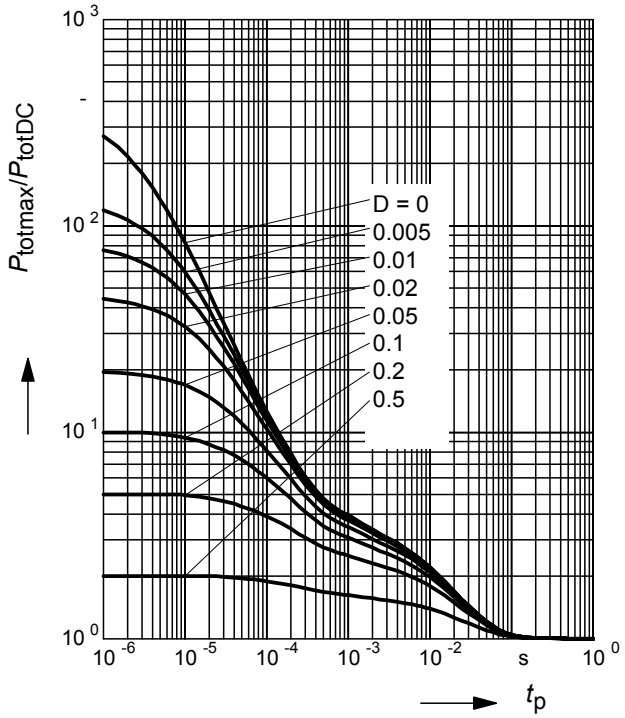
SMBT3906S



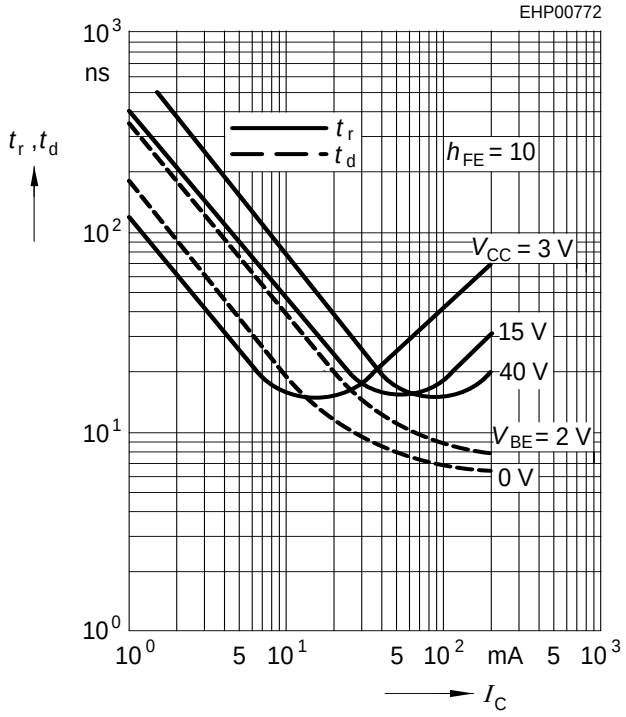
Permissible Pulse Load

$P_{totmax}/P_{totDC} = f(t_p)$

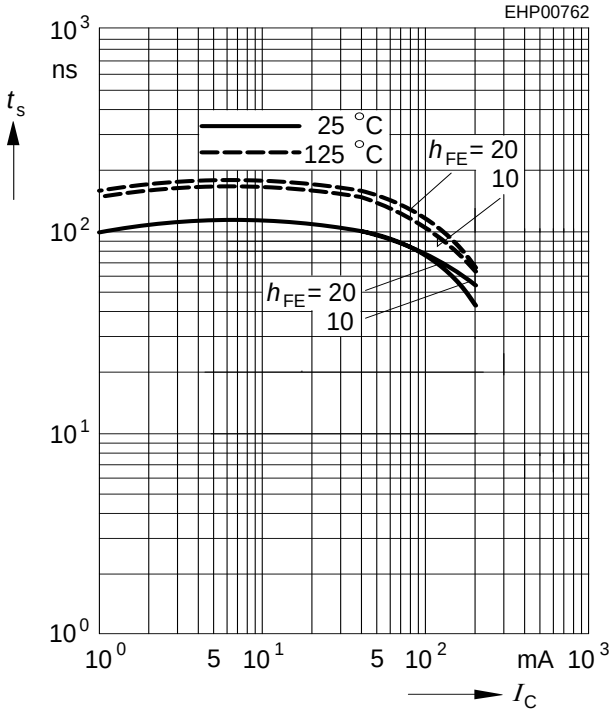
SMBT3906S



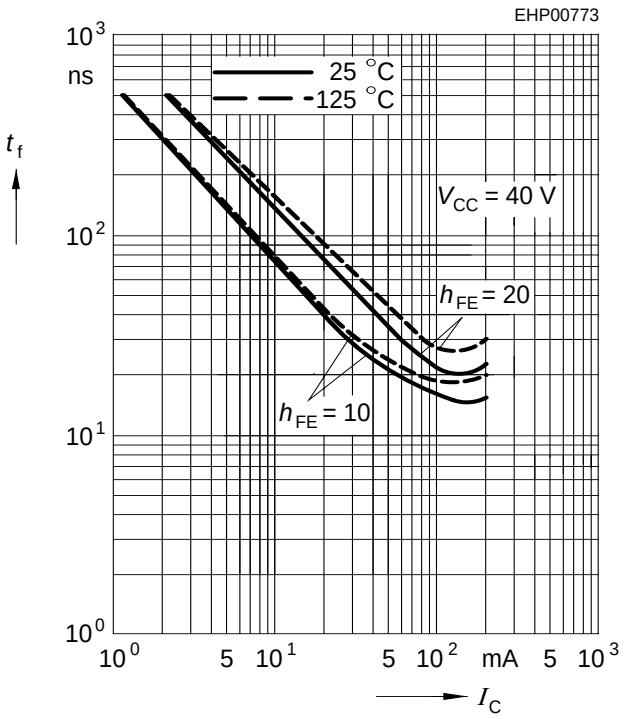
Delay time t_d = $f(I_C)$
Rise time t_r = $f(I_C)$



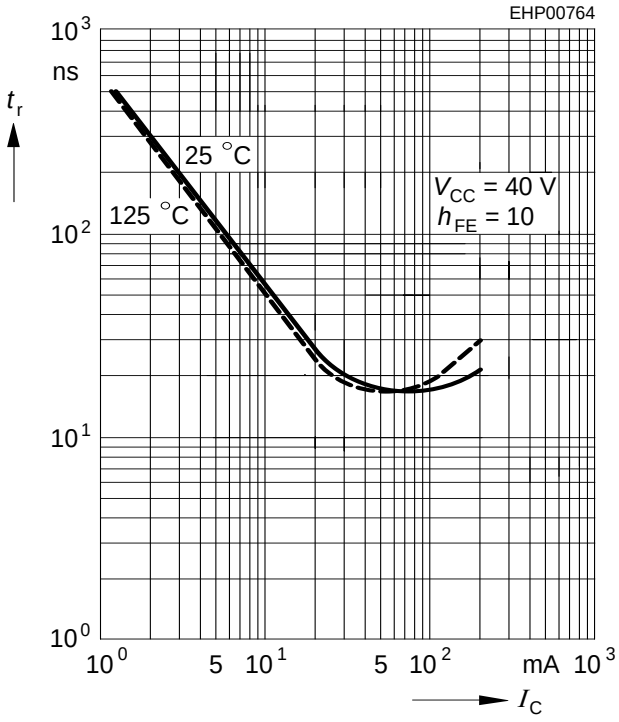
Storage time t_{stg} = $f(I_C)$



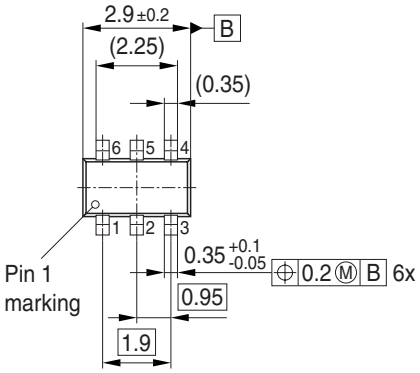
Fall time t_f = $f(I_C)$

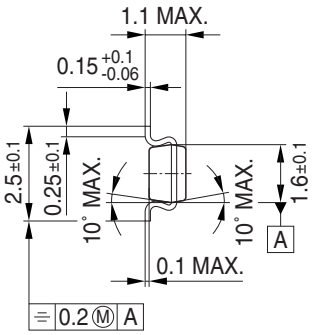


Rise time t_r = $f(I_C)$

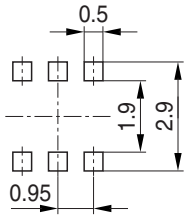


Package Outline



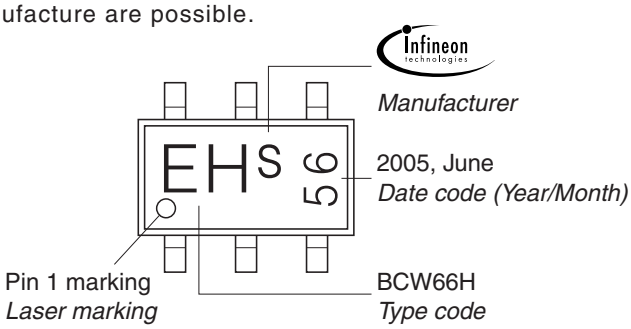


Foot Print



Marking Layout (Example)

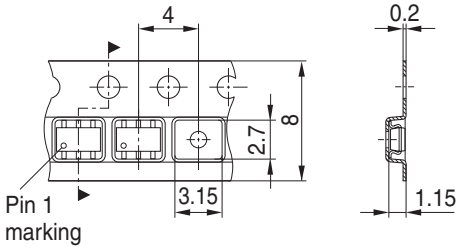
Small variations in positioning of
Date code, Type code and Manufacture are possible.



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.



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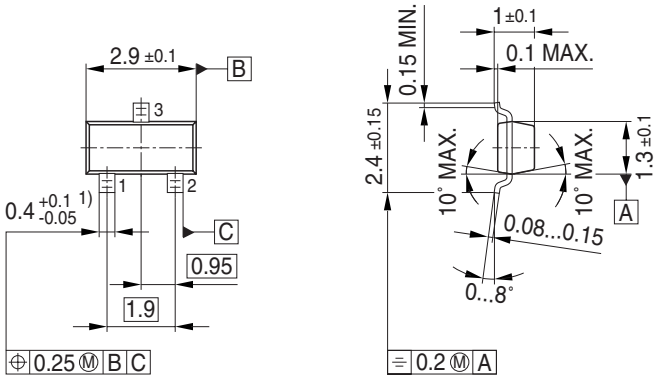
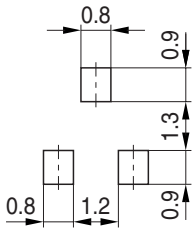


1) Lead width can be 0.6 max. in dambar area

Foot Print



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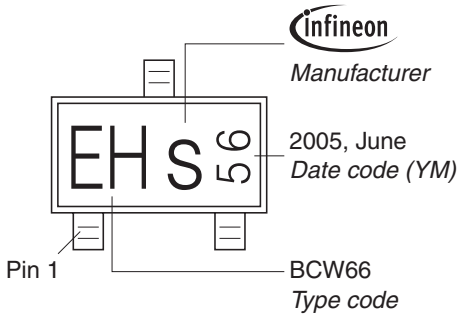

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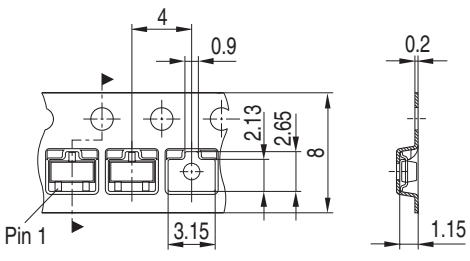

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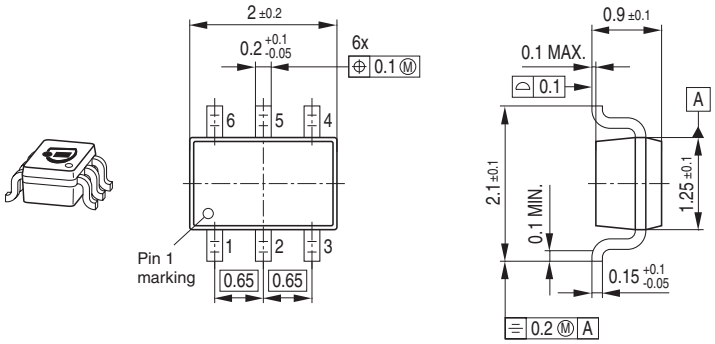

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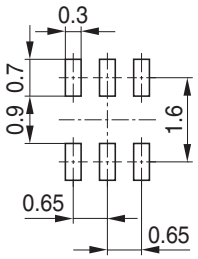

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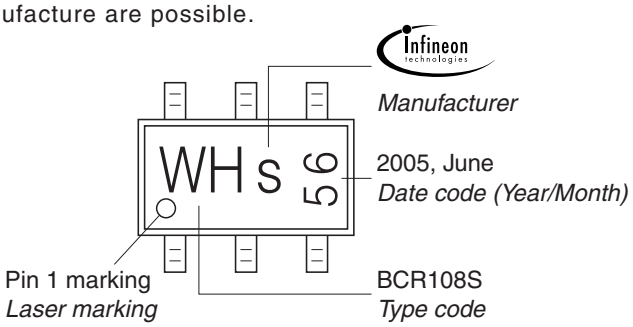

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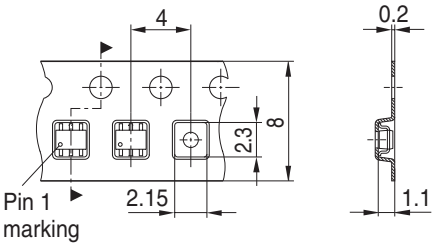

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OCEAN CHIPS
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- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
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- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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AVIC JONHON

«JONHON» (основан в 1970 г.)

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(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

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FORSTAR®

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